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INFORMATION DISCLOSURE CITATION
 (Use several sheets if necessary)

Docket Number (Optional)	Application Number
P-6244 (3008-2-008003)	10/035,672 75
Applicant(s) WANG et al.	
Filing Date	Group Art Unit
11/01/2001	1765

U.S. PATENT DOCUMENTS

INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
<i>MAA</i>		5,968,261	10/19/1999	Barrett et al.			
<i>MAA</i>		5,746,827	05/05/1998	Barrett et al.			
<i>MAA</i>		5,441,011	08/15/1995	Takahaski et al.			
<i>MAA</i>		Re. 34,861	02/14/1995	Davis et al.			
<i>MAA</i>		4,866,005	09/12/1989	Davis et al.			

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 TC 1700

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO
<i>MAA</i>		EP 1 143 493 A2	10/10/2001	EUROPE				
<i>MAA</i>		WO 01/04391 A1	01/18/2001	WIPO			Abstract	
<i>MAA</i>		EP 0 712 150 A1	05/15/1996	EUROPE				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

<i>MAA</i>	N. Schulze et al., "Near-equilibrium growth of micropipe-free 6H-SiC single crystals by physical vapor transport" Applied Physics Letters, Vo. 72, No. 13, March 30, 1998, pp. 1632-1634
<i>MAA</i>	Material Science - Silicon Carbide (www.ifm.liu.se/matephys/AAnew/research/sicpart/sicindex.html), August 28, 2001, 22 pgs. <i>MAA 9/6/03</i>

EXAMINER <i>Matthew Anderson</i>	DATE CONSIDERED <i>9/6/03</i>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.